



40V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET POWERDI®

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C (Note 9)
40V	$7.6 \text{m}\Omega$ @ $V_{GS} = 10V$	100A

Description

This new generation N-Channel Enhancement Mode MOSFET is designed to minimize $R_{\text{DS(ON)}}$, yet maintain superior switching performance. This device is ideal for use in notebook battery power management and loadswitch.

Applications

- Power Management
- DC-DC Converters
- Motor Control

Features

- Rated to +175°C Ideal for High Ambient Temperature Environments
- Thermally Efficient Package-Cooler Running Applications
- High Conversion Efficiency
- Low R_{DS(ON)} Minimizes On State Losses
- Low Input Capacitance
- Fast Switching Speed
- <1.1mm Package Profile Ideal for Thin Applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- An Automotive-Compliant Part is Available Under Separate Datasheet (DMTH4007SPSQ)

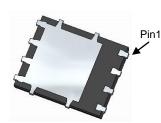
Mechanical Data

- Case: POWERDI[®] 5060-8
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)

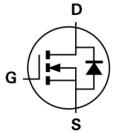
POWERDI[®]5060-8



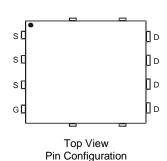
Top View



Bottom View



Internal Schematic



Ordering Information (Note 4)

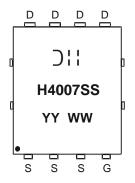
Part Number	Case	Packaging	
DMTH4007SPS-13	POWERDI [®] 5060-8	2,500 / Tape & Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.



Marking Information



☐ H = Manufacturer's Marking H4007SS = Product Type Marking Code YYWW = Date Code Marking YY = Last Digit of Year (ex: 14 = 2014) WW = Week Code (01 to 53)

Maximum Ratings ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic		Symbol	Value	Units
Drain-Source Voltage		V_{DSS}	40	V
Gate-Source Voltage		V_{GSS}	±20	V
Continuous Drain Current (Note 5)	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	15.7 13.1	А
Continuous Drain Current (Note 6)	$T_{C} = +25^{\circ}C$ (Note 9) $T_{C} = +100^{\circ}C$	I _D	100 77	А
Maximum Continuous Body Diode Forward Current (Note 6)		I _S	100	Α
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I _{DM}	120	Α
Avalanche Current, L=0.3mH		I _{AS}	20	Α
Avalanche Energy, L=0.3mH		E _{AS}	60	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	P_{D}	2.8	W
Thermal Resistance, Junction to Ambient (Note 5)		$R_{ heta JA}$	53	°C/W
Total Power Dissipation (Note 6) $T_C = +25^{\circ}C$		P _D	136	W
Thermal Resistance, Junction to Case (Note 6)		$R_{ heta JC}$	1.1	°C/W
Operating and Storage Temperature Range		$T_{J_i}T_{STG}$	-55 to +175	°C

5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate. 6. Thermal resistance from junction to soldering point (on the exposed drain pad). Notes:



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

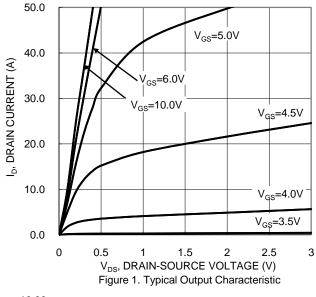
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	40	_	_	V	$V_{GS} = 0V$, $I_D = 1mA$	
Zero Gate Voltage Drain Current	I _{DSS}	l	_	1	μA	$V_{DS} = 32V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)						•	
Gate Threshold Voltage	V _{GS(TH)}	2	_	4	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	l	4.9	7.6	mΩ	$V_{GS} = 10V, I_D = 20A$	
Diode Forward Voltage	V_{SD}	_	_	1.2	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C _{iss}	l	2,082)/ OF)/)/ O)/	
Output Capacitance	Coss	_	790	_	pF	$V_{DS} = 25V$, $V_{GS} = 0V$, f = 1MHz	
Reverse Transfer Capacitance	C _{rss}	_	113	_			
Gate Resistance	Rg	_	0.46	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge	Q_{g}	_	41.9	_			
Gate-Source Charge	Q _{gs}	_	10	_	nC	$V_{DS} = 30V, I_D = 20A, V_{GS} = 10V$	
Gate-Drain Charge	Q_{gd}	_	11.5	_			
Turn-On Delay Time	t _{D(ON)}	_	7	_		$V_{DD} = 30V, V_{GS} = 10V,$ $I_{D} = 20A, R_{G} = 3\Omega$	
Turn-On Rise Time	t _R	_	11.5	_			
Turn-Off Delay Time	t _{D(OFF)}	_	15.6	_	ns		
Turn-Off Fall Time	t _F	_	8.8	_			
Body Diode Reverse Recovery Time	t _{RR}	_	29.9	_	ns	1 004 11/11 4004/	
Body Diode Reverse Recovery Charge	Q_{RR}	_	23	_	nC	$I_F = 20A$, di/dt = 100A/ μ s	

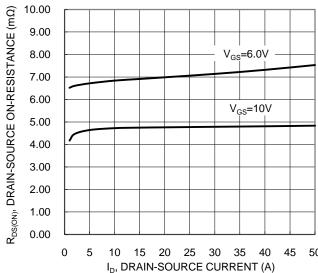
^{7.} Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to product testing.
9. Package limited.

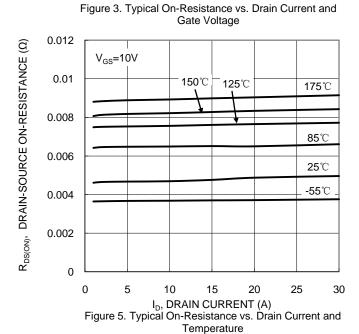


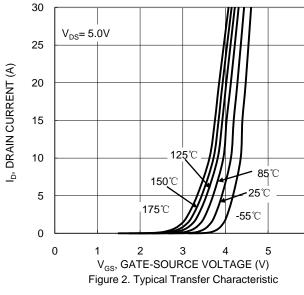
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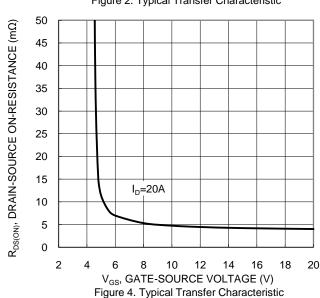












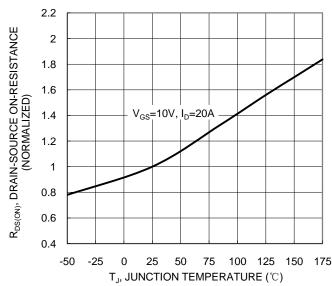


Figure 6. On-Resistance Variation with Temperature



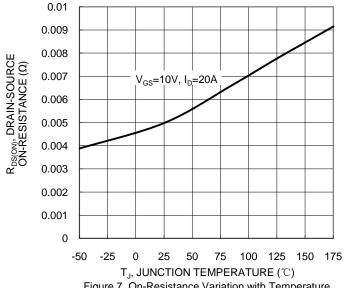
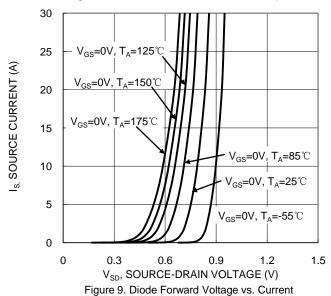
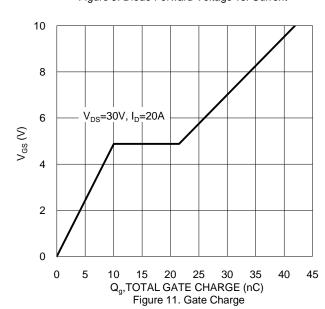


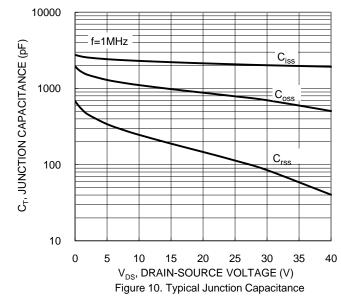
Figure 7. On-Resistance Variation with Temperature





4 $V_{GS(TH)},$ GATE THRESHOLD VOLTAGE (V) 3.5 3 2.5 $I_D=1mA$ 2 $I_{D} = 250 \mu A$ 1.5 0.5 -50 50 75 100 125 150 175 T_J, JUNCTION TEMPERATURE (°C)

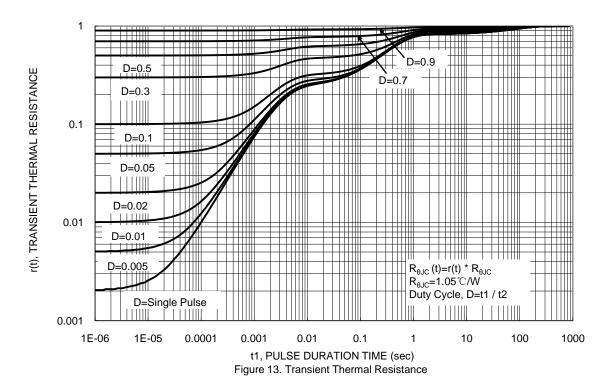
Figure 8. Gate Threshold Variation vs. Temperature



1000 R_{DS(on)} Limited ID, DRAIN CURRENT (A) 100 10 $T_C = 25^{\circ}C$ $V_{GS} = 10V$ Single Pulse DUT on Infinite Heatsink 10 100 V_{DS}, DRAIN-SOURCE VOLTAGE (V) Figure 12 SOA, Safe Operation Area

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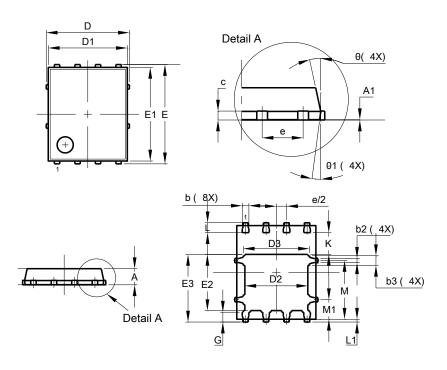




Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

POWERDI®5060-8

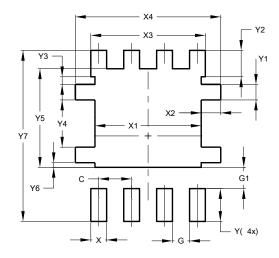


POWERDI5060-8					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	_		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D	Į	5.15 BSC	;		
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
Е	6	3.15 BSC	;		
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е	1.27 BSC				
G	0.51	0.71	0.61		
K	0.51	_	_		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
M	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

POWERDI®5060-8



Dimensions	Value (in mm)			
C	1.270			
G	0.660			
G1	0.820			
Х	0.610			
X1	4.100			
X2	0.755			
Х3	4.420			
X4	5.610			
Υ	1.270			
Y1	0.600			
Y2	1.020			
Y3	0.295			
Y4	1.825			
Y5	3.810			
Y6	0.180			
Y7	6.610			



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